

32. Template for Course Plan of Electronics 2

I. Information about Faculty Member Responsible for the Course:							
Name of Faculty Member	Asst. Prof. Dr. Abdulkafi Al-Eriany	Office Hours					
Location & Telephone No.		SAT SUN MON TUE WED THU			THU		
E-mail							

II. Course Identification and General Information:						
1.	Course Title:	Electro	nics 2			
2.	Course Number & Code:	PME21	4			
			C.I	Ŧ		Total
3.	Credit hours:	Th.	Tu.	Pr.	Tr.	Total
		2	2	2	-	4
4.	Study level/year at which this course is offered:	Level 3- Semester 1				
5.	Pre –requisite (if any):	Electronics 1(PME113)				
6.	Co –requisite (if any):	None.				
7.	Program (s) in which the course is offered	Electric	cal Engine	eering D	Departm	ent
8.	Language of teaching the course:	English	ı & Arabi	с		
9.	System of Study:	Regula	r			
10.	Mode of delivery:	Semesters				
Inside the University, Faculty of			culty of	f		
11.	Location of teaching the course:		Engineering Electrical Engineering Department			

Prepared by

Head of Department Asst. Prof. Dr. Adel Ahmed Al-Shakiri Quality Assurance Unit Assoc. Prof. Dr. Mohammad Algorafi Dean of the Faculty Prof. Dr. Mohammed AL-Bukhaiti Academic Development Center & Quality Assurance Assoc. Prof. Dr. Huda Al-Emad



III. Course Description:

This course is a continuation of Electronic Circuits 1 for advanced applications. The topics include BJTs and FETs frequency response. The course also discusses the main properties and parameters of different classes of power amplifiers including the solution of power efficiency of each class & Analog-to- Digital Converters (A/D) & Digital-to-Analog Converters (D/A). The course has an associated Laboratory experiments set, which will require use of simulation software and hardware equipment. Later, the course will introduce a basic definition, concepts, and design of digital logic circuits such as DTL, TTL. ECL, MOS & CMOS etc.

IV.Intended learning outcomes (ILOs) of the course:

- Brief summary of the knowledge or skill the course is intended to develop:
 - 1. Demonstrate knowledge of developed characteristics, operations, fundamental laws and analysis, and engineering applications related to electronic circuits and systems.
 - **2.** Define principles of design including elements, processes and/or systems related to electronic program.
 - 3. Solve electronics systems using appropriate methods and modeling techniques.
 - **4.** Analyze the electronics engineering in the field of industrial products.
 - **5.** Employ the international standards and technical specifications of analog electronics components while designing and integrating electronic systems.
 - **6.** Conduct laboratory experiments safely to verify theoretical concepts related to electronics components and devices.
 - **7.** Assess personal commitment to electronics engineering tasks and effectively manage time and resources.

V.	V. Course Content:					
A – The	A – Theoretical Aspect:					
Order	Units/Topics List	Sub Topics List	Number of Weeks	Contact hours		

Prepared by

Head of Department Asst. Prof. Dr. Adel Ahmed Al-Shakiri Quality Assurance Unit Assoc. Prof. Dr. Mohammad Algorafi Dean of the Faculty Prof. Dr. Mohammed AL-Bukhaiti Academic Development Center & Quality Assurance Assoc. Prof. Dr. Huda Al-Emad







1.	BJT Frequency response	General Frequency Consideration.Types of Coupling.	1 st	2
2.	BJT Frequency response	 R-C Circuits. Logarithms and Decibel Concepts. Low Frequency analysis. Bode plot 	2 nd	2
3.	FET Frequency analysis	 Low Frequency Analysis. Bode Plot.	$3^{ m rd}$	2
4.	BJT and FET Frequency Response	Miller Effect.Input & output Miller Capacitances.High Frequency Analysis.	4 th	2
5.	Power amplifiers	 Main properties and Characteristics of power amplifiers. 	5 th	2
6.	Power amplifiers	 Classes of Power Amplifier. Power Efficiency. Series-Fed Class A Power Amplifier. Class B Power Amplifier Power Efficiency. 	6 th	2
7.	Power amplifiers	 Class AB Power Amplifier. Class C and Class D Power Amplifiers. Main properties and utilization. 	7 th	2
8.	Midterm exam	All previous topics	8 th	2
9.	Analog-to digital converters (A/D)	 Successive Approximation A/D Converter. Dual-Slop (Dual-Ramp) A/D Converter. 	9 th	2

Prepared by

Head of Department Asst. Prof. Dr. Adel Ahmed Al-Shakiri Quality Assurance Unit Assoc. Prof. Dr. Mohammad Algorafi Dean of the Faculty Prof. Dr. Mohammed AL-Bukhaiti Academic Development Center & Quality Assurance Assoc. Prof. Dr. Huda Al-Emad









		• Parallel A/DE Converter (Flash Adder)		
10.	Digital-to analog converters (D/A)	 D/A Converter using Binary Weighted Resistor. D/A Converter using R-2R Resistance Ladder. 	10 th	2
11.	Logic circuits	Introduction to logic circuits.Review of Boolean Algebra.Timing Diagrams.	11 th	2
12.	Noise margin analysis Power consumption of logic gates	 Dynamic Response of Logic Gates. Rise Time and Fall Times Propagation Time. Propagation Delay. Noise immunity. 	12 th	2
13.	DTL & TTL circuits	 Diode Resistor OR Gate. Diode Resistor AND Gate. Diode Transistor Logic (DTL). Transistor Transistor Logic (TTL). 	13 th	2
14.	Other types of logic circuits.	ECL Logic Gate.MOC & CMOS Logic Gates.	14 th	2
15.	Overview	• All Topics	15 th	2
16.	Final exam	• All Topics	16 th	2
Numbe	r of Weeks /and Units	Per Semester	16	32

B – Tu	B – Tutorial Aspect:					
Order	Units/Topics List	Sub Topics List	Number of Weeks	Contact hours		
1.	BJT Frequency response	General Frequency Consideration.Types of Coupling.	1 st	2		

Prepared by

Head of Department Asst. Prof. Dr. Adel Ahmed Al-Shakiri Quality Assurance Unit Assoc. Prof. Dr. Mohammad Algorafi Dean of the Faculty Prof. Dr. Mohammed AL-Bukhaiti Academic Development Center & Quality Assurance Assoc. Prof. Dr. Huda Al-Emad







2.	BJT Frequency response	 R-C Circuits. Logarithms and Decibel Concepts. Low Frequency analysis. Bode plot 	2 nd	2
3.	FET'S Frequency analysis	Low Frequency Analysis.Bode Plot.	3 rd	2
4.	BJT and FETS Frequency Response	Miller Effect.Input & output Miller Capacitances.High Frequency Analysis.	4 th	2
5.	Power amplifiers	 Main properties and Characteristics of power amplifiers. 	5 th	2
6.	Power amplifiers	 Classes of Power Amplifier. Power Efficiency. Series-Fed Class a Power Amplifier. Class B Power Amplifier Power Efficiency. 	6 th	2
7.	Power amplifiers	 Class AB Power Amplifier. Class C and Class D Power Amplifiers. Main properties and utilization. 	7 th	2
8.	Midterm exam	 All previous topics 	8 th	2
9.	Analog-to digital converters (A/D)	 Successive Approximation A/D Converter. Dual-Slop (Dual-Ramp) A/D Converter. Parallel A/DE Converter (Flash Adder) 	9 th	2
10.	Digital-to analog converters (D/A)	 D/A Converter using Binary Weighted Resistor. 	10 th	2

Prepared by

Head of Department Asst. Prof. Dr. Adel Ahmed Al-Shakiri Quality Assurance Unit Assoc. Prof. Dr. Mohammad Algorafi Dean of the Faculty Prof. Dr. Mohammed AL-Bukhaiti

Academic Development Center & Quality Assurance Assoc. Prof. Dr. Huda Al-Emad









		■ D/A Converter using R-2R		
		Resistance Ladder.		
		■ Introduction to logic circuits.	a a th	
11.	Logic circuits	Review of Boolean Algebra.	11 th	2
		■ Timing Diagrams.		
	Noise margin	 Dynamic Response of Logic Gates. 		
	analysis	Rise Time and Fall Times		
12.	Power	Propagation Time.	12 th	2
	consumption of	Propagation Delay.		
	logic gates	■ Noise immunity.		
		■ Diode Resistor OR Gate.		
12	DTL & TTL	Diode Resistor AND Gate.	13 th	2
13.	circuits	■ Diode Transistor Logic (DTL).	13	2
		■ Transistor Transistor Logic (TTL).		
14.	Other types of	■ ECL Logic Gate.	14 th	2
14.	logic circuits.	■ MOC & CMOS Logic Gates.	14	2
15.	Overview	■ All Topics	15 th	2
16.	Final exam	■ All Topics	16 th	2
Numbe	r of Weeks /and Uni	ts Per Semester	16	32

C – Practical Aspect:					
Order	Tasks/ Experiments	Number of Weeks	Contact hours		
1.	BJT – Frequency response	1 st	2		
2.	FET – Frequency response	2 nd	2		
3.	BJT and FET's Frequency response	3 rd	2		
4.	BJT and FET's Frequency response	4 th	2		
5.	Series-Fed Class a Power amplifier. Input power, output power and power efficiency	5 th	2		

Prepared by	Head of Department	Quality Assurance Unit	Dean of the Faculty	Academic Development
	Asst. Prof. Dr. Adel	Assoc. Prof. Dr.	Prof. Dr. Mohammed	Center & Quality Assurance
	Ahmed Al-Shakiri	Mohammad Algorafi	AL-Bukhaiti	Assoc. Prof. Dr. Huda Al-Emad









6.	Class B power Amplifier, input power, output power and power efficiency	6 th	2
7.	Class AB Power Amplifier	7^{th}	2
8.	Class C and Class D Power Amplifiers	8 th	2
9.	Analog-to- Digital Converters (A/D) & Digital-to-Analog Converters (D/A)	9 th	2
10.	Determination of Dynamic Characteristics of Logic Circuits Determination of Margin Time of Logic Circuits	10 th	2
11.	DRL & DTL (Input & Output Measurement) Rise- Time and Fall-Time Logic Circuits	11 th	2
12.	Design of TTL & ECL Logic Circuits Design of MOS & CMOS Logic Circuits	12 th	2
13.	Final Hand-Work or Project	13 th	2
14.	Review	14 th	2
15.	Final Practical Exam	15 th	2
Numbe	r of Weeks /and Units Per Semester	15	30

VI. Teaching strategies of the course:

- Lectures.
- Tutorials.
- Laboratory.
- Seminar.
- Interactive class discussion.

	VII.Assignments:						
No	Assignments	Aligned CILOs (symbols)	Week Due	Mark			
1.	BJT & FET (Low frequency response).	a1, a2, b1, c1, c2	3 th & 4 th	4			
2.	BJT & FET	a1, a2, b1, c1, c2	5 th & 6 th	4			

Prepared by

Head of Department Asst. Prof. Dr. Adel Ahmed Al-Shakiri Quality Assurance Unit Assoc. Prof. Dr. Mohammad Algorafi Dean of the Faculty Prof. Dr. Mohammed AL-Bukhaiti Academic Development Center & Quality Assurance Assoc. Prof. Dr. Huda Al-Emad









	(High frequency response).			
3.	Series Fed class A power amplifier	a1, a2, b1, b2, c1, c2, d1	8 th & 9 th	4
4.	Class B power amplifier. Class AB, C, D	a1, a2, b1, b2, c1, c2, d1	10 th & 11 th	4
5.	Logic Circuits	a1, a2, b1, b2, c1, c2, d1	12 th & 13 th	4
Total			20	

VIII.Schedule of Assessment Tasks for Students During the Semester:

No.	Assessment Method	Week Due	Mark	Proportion of Final Assessment
1.	Assignments& Homework	3 rd to 13 th	20	10%
2.	Lab work and experiments reports	4 th to 13 th	20	10%
3.	Practical Term-Project and Presentation	3 rd to 14 th	20	10%
4.	Mid-Term Exam (Theoretically)	8 th	20	10%
5.	Final-Term Exam (Practically)	15 th	20	10%
6.	Final-Term Exam (Theoretically)	16 th	100	50%
	Total Assessments Mark/Percentage			100%

IX. Learning Resources:

Written in the following order: (Author - Year of publication – Title – Edition – Place of publication – Publisher).

1- Required Textbook(s) (maximum two).

- **1.** Robert L. Boylestad, Louis Nashelsky, 2013, Electronic Devices and Circuit Theory, Prentice Hall, 11th Edition.
- 2. Thomas L. Floyd, 2012, Electronic devices, 9th Ed, USA, Pearson Prentice Hall.

Prepared by

Head of Department Asst. Prof. Dr. Adel Ahmed Al-Shakiri Quality Assurance Unit Assoc. Prof. Dr. Mohammad Algorafi Dean of the Faculty Prof. Dr. Mohammed AL-Bukhaiti Academic Development Center & Quality Assurance Assoc. Prof. Dr. Huda Al-Emad



2- Essential References.

- 1. Robert T. Paynter, 2006, Introductory to Electronic Devices and Circuits, Printice Hall.
- 2. J. Millman & A. Garbel -1978 "Microelectronics", McGraw Hill.
- 3. S. H. Grove 1997 "Semiconductor physics and devices", John Wiley.
- **4.** Sedra & K. Smith 1998 "Microelectronic Circuits", Holt, Rinehart and Winston.
- **5.** Richard C. Jaeger and Travis N. Blalock 2011 Microelectronic 1 NIC circuit Design 4/Edition McGraw Hill Companies, USA New York.

3- Electronic Materials and Web Sites etc.

- 1. http://www.ocw.mit.edu/courses.
- **2.** https://www.youtube.com/playlist?list=PLww54WQ2wa5rOJ7FcXxi-CMNgmpybv7ei
- **3.** Lectures will be prepared by lecturer.
- 4. Faculty Electronic Library.

X	. Course Policies:		
1.	Class Attendance: A student should attend not less than 75 % of total hours of the subject; otherwise he will not be able to take the exam and will be considered as exam failure. If the student is absent due to illness, he/she should bring an approved statement from university Clinic		
2.	Tardy: For late in attending the class, the student will be initially notified. If he repeated lateness in attending class he will be considered as absent.		
3.	Exam Attendance/Punctuality: A student should attend the exam on time. He is Permitted to attend an exam half one hour from exam beginning, after that he/she will not be permitted to take the exam and he/she will be considered as absent in exam-		
4.	Assignments & Projects: The assignment is given to the students after each chapter; the student has to submit all the assignments for checking on time-		
5.	Cheating:		

Prepared by

Head of Department Asst. Prof. Dr. Adel Ahmed Al-Shakiri Quality Assurance Unit Assoc. Prof. Dr. Mohammad Algorafi Dean of the Faculty Prof. Dr. Mohammed AL-Bukhaiti Academic Development Center & Quality Assurance Assoc. Prof. Dr. Huda Al-Emad



	For cheating in exam, a student will be considered as failure. In case the cheating is		
	repeated three times during his/her study the student will be disengaged from the Faculty-		
	Plagiarism:		
	Plagiarism is the attending of a student the exam of a course instead of another student.		
6.	If the examination committee proved a plagiarism of a student, he will be disengaged		
	from the Faculty. The final disengagement of the student from the Faculty should be		
	confirmed from the Student Council Affair of the university.		
	Other policies:		
	- Mobile phones are not allowed to use during a class lecture. It must be closed, otherwise		
7.	the student will be asked to leave the lecture room		
	- Mobile phones are not allowed in class during the examination.		
	Lecture notes and assignments my given directly to students using soft or hard copy		

Prepared by

Head of Department Asst. Prof. Dr. Adel Ahmed Al-Shakiri Quality Assurance Unit Assoc. Prof. Dr. Mohammad Algorafi Dean of the Faculty Prof. Dr. Mohammed AL-Bukhaiti Academic Development Center & Quality Assurance Assoc. Prof. Dr. Huda Al-Emad









Prepared by I

Head of Department Asst. Prof. Dr. Adel Ahmed Al-Shakiri Quality Assurance Unit Assoc. Prof. Dr. Mohammad Algorafi Dean of the Faculty Prof. Dr. Mohammed AL-Bukhaiti Academic Development Center & Quality Assurance Assoc. Prof. Dr. Huda Al-Emad